

Product Overview

BDW46: 15 A, 80 V PNP Darlington Bipolar Power Transistor

For complete documentation, see the data sheet.

This series of plastic, medium-power NPN and PNP Darlington transistors are designed for general purpose and low speed switching applications. The BDW42, BDW46 and BDW47 are complementary devices.

Features

- High DC Current Gain h_{FE} = 2500 (typ.) @ I_C = 5.0 Adc.
- Collector Emitter Sustaining Voltage @ 30 mAdc: $V_{CEO(sus)}$ = 80 Vdc (min.) BDW46 $V_{CEO(sus)}$ = 100 Vdc (min.) BDW42/BDW47
- Low Collector Emitter Saturation Voltage $V_{CE(sat)}$ = 2.0 Vdc (max.) @ I_C = 5.0 Adc $V_{CE(sat)}$ = 3.0 Vdc (max.) @ I_C = 10.0 Adc
- · Monolithic Construction with Built-In Base Emitter Shunt resistors
- TO-220AB Compact Package
- · Pb-Free Packages are Available

Part Electrical Specifications										
Product	Compliance	Status	Polarity	I _C Continuous (A)	V _{(BR)CEO} Min (V)	V _{CE(sat)} Max (V)	h _{FE} Min (k)	h _{FE} Max (k)	f _T Min (MHz)	Package Type
BDW46G	Pb-free	Active	PNP	15	80	2	1	-	4	TO-220-3

For more information please contact your local sales support at www.onsemi.com.

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